Large-area optical coatings grown by Spatial ALD

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Abstract



- Spatial ALD, substrate temperature 150 °C
- Prototype Beneq SCS1000 reactor
- Substrate size 400 x 500 mm, borosilicate glass (n \approx 1.52)
- Multilayer films
 - $AI_2O_3 [TMA+H_2O]$
 - $ZnS [(C_2H_5)_2Zn, DEZ + H_2S]$
- Good optical thickness control, process stability

Introduction - Spatial ALD (1/3)



- Precursors enter substrate through coating head
- Precursors separated by inert gas zones
- Substrate or coating head moves, covering whole substrate
- Film is formed, thickness controlled by number of precursor passes
- One pass can be one or more growth cycles depending on coating head configuration



Schematic of Spatial ALD working principle. Figure adapted from [1].

Introduction - Optical films (2/3)



- Manipulation of reflectance or transmittance for a substrate
- Wavelength ranges vary for deep UV (≈220 nm) to IR (> 800 nm)
- Typically consisting of transparent, lossless thin film materials
 - E.g. TiO_2 , Ta_2O_5 , ZnS, HfO₂, Al₂O₃, SiO₂, MgF₂
- Index difference between two films causes thin film interference
- ALD suitable due to
 - Digital control of layer thickness
 - Construction of effective/"new" materials (e.g. multilayers, laminates)

Introduction - Spatial ALD + Optical films (3/3)

- Spatial ALD appealing as a method to produce optical films with possibilities including
 - Improved process time vs. pulsed ALD
 - Capability to produce thick coatings
 - Possibility for large substrates



Beneq SCS1000 ALD reactor



Figures (C) Beneq Oy

Experimental (1/3)



 Choose high and low index materials as ZnS [DEZ, H₂S] and Al₂O₃ [TMA+H₂O] from preliminary testing at 150 °C



EDX data for 150 °C grown ZnS on Si by Spatial ALD. [2]

[2] Heikkinen, I.T.S. 2016. Characterization of Zinc Oxide, Sulfide and Oxysulfide Thin Films Grown By Spatial Atomic Layer Deposition. Master's Thesis. Aalto University School of Science.



Experimental (2/3)



- Determination of optical constants
 - Spectrophotometric measurement of transmission
 - Fitting data to a dispersion model (Cauchy)



Experimental (3/3)



- Construction of optical coatings
- Deposition at identical parameters to single films
 - Pressure 50 mbar
 - Carrier gas flow 0.5 SLM per nozzle
 - Substrate temperature 150 °C
- Substrate size 400 x 500 mm glass

Film	Growth rate (nm/c)	Line speed (m/min)
ZnS	0.12	9
Al ₂ O ₃	0.13	9

Results - Anti-reflective coatings (1/5)

- 1. Sensitive design, 400 x 500 mm glass
 - 6 layers, total thickness 240 nm



Results - Anti-reflective coatings (2/5)

- 2. Insensitive design, 400 x 500 mm glass
 - 8 layers, total thickness 457 nm



Results - Mirrorlike infrared-pass filter (3/5)

- Total thickness 1450 nm
- High reflectance in visible range (mirrorlike appearance), passes infrared light through



Results - Mirrorlike infrared-pass filter (4/5)

- Performance measured from 9 points spanning substrate •
- High R zone, $R_{avg} > 84 \% (400-750 \text{ nm})$ Low R zone, $R_{avg} = 17 \% (800-1050 \text{ nm})$ Deviation causes from design speculated as ٠
 - Total optical thickness too high -> systematic error in GPC of either material?
 - Unaccounted losses -> scattering from ZnS?



Results (5/5)





Summary (1/2)



- Optical coatings by Spatial ALD using Al₂O₃ and ZnS at 150 °C on large glass substrates demonstrated
- Optical thickness control for non-repeating thickness layers without in-situ monitoring possible even for thick films

Summary (2/2)



- Further research could target
 - Increased number of possible optical films
 - Homogeneity of films, film growth with spatial ALD
 - Methods to achieve higher throughputs, faster process times
 - Applications where conformality is key [3], e.g. diffractive gratings

References



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- [2] Heikkinen, I.T.S. 2016. Characterization of Zinc Oxide, Sulfide and Oxysulfide Thin Films Grown By Spatial Atomic Layer Deposition. Master's thesis. Aalto University School of Science.
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